

PACKAGE MARKING AND ORDERING INFORMATION

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
SSF3610	SSF3610	SOP-8	Ø330mm	12mm	3000 units

ABSOLUTE MAXIMUM RATINGS(TA=25 °C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	30	V
Gate-Source Voltage	V _{GS}	±20	V
	l₀(25℃)	11	А
Drain Current-Continuous@ Current-Pulsed (Note 1)	l₀(70℃)	8.6	А
	I _{DM}	50	А
Maximum Power Dissipation	PD	2	W
Operating Junction and Storage Temperature Range	T _J ,T _{STG}	-55 To 150	°C

THERMAL CHARACTERISTICS

Thermal Resistance, Junction-to-Ambient (Note 2)	R _{0JA}	62.5	°C/W
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ELECTRICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250µA	30			V



Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =30V, V_{GS} =0V		1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V		±100	nA
ON CHARACTERISTICS (Note 3)					I
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_D=250\mu A$	1 1	.9 3	V
Drain-Source On-State Resistance	P	V _{GS} =4.5V, I _D =8A	9	.5 13	mΩ
	R _{DS(ON)}	V_{GS} =10V, I_D =11A	6	.5 9	mΩ
Forward Transconductance	g fs	V _{DS} =5V,I _D =11A	2	0	S
DYNAMIC CHARACTERISTICS (Note4)					
Input Capacitance	C _{lss}		12	00	PF
Output Capacitance	Coss	V _{DS} =25V,V _{GS} =0V, F=1.0MHz		00	PF
Reverse Transfer Capacitance	C _{rss}		1:	20	PF
SWITCHING CHARACTERISTICS (Note 4)					
Turn-on Delay Time	t _{d(on)}		1	0	nS
Turn-on Rise Time	tr	V _{DS} =15V,V _{GS} =10V,R _{GEN} =6Ω	6	.5	nS
Turn-Off Delay Time	t _{d(off)}	I _D =1A	2	5	nS
Turn-Off Fall Time	t _f]	9	.7	nS
Total Gate Charge	Qg		1	2	nC
Gate-Source Charge	Q _{gs}	V _{DS} =15V,I _D =12A,V _{GS} =10V	3	.2	nC
Gate-Drain Charge	Q _{gd}		3	.8	nC
Body Diode Reverse Recovery Time	T _{rr}		2	4	nS
Body Diode Reverse Recovery Charge	Q _{rr}	− I _F =12A, dl/dt=100A/μs −	2	7	nC
DRAIN-SOURCE DIODE CHARACTERISTIC	S	· · ·	1	•	•
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =2.3A	0.	74 1.2	V

NOTES:

Repetitive Rating: Pulse width limited by maximum junction temperature.
 Surface Mounted on 1in² FR4 Board, t ≤ 10 sec.
 Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
 Guaranteed by design, not subject to production testing.



TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

Vgs Rgen G S Vout



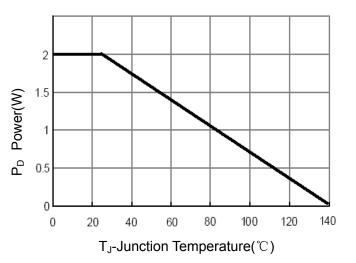


Figure 3 Power Dissipation

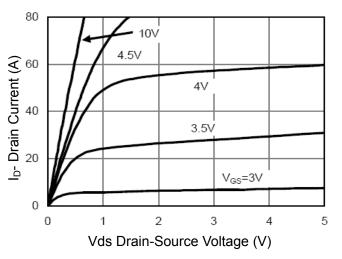


Figure 5 Output CHARACTERISTICS

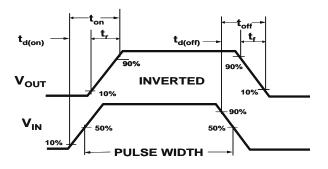


Figure 2:Switching Waveforms

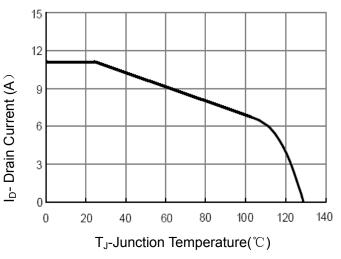


Figure 4 Drain Current

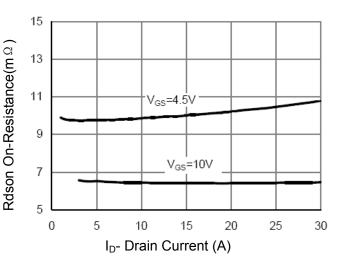


Figure 6 Drain-Source On-Resistance



SSF3610

150

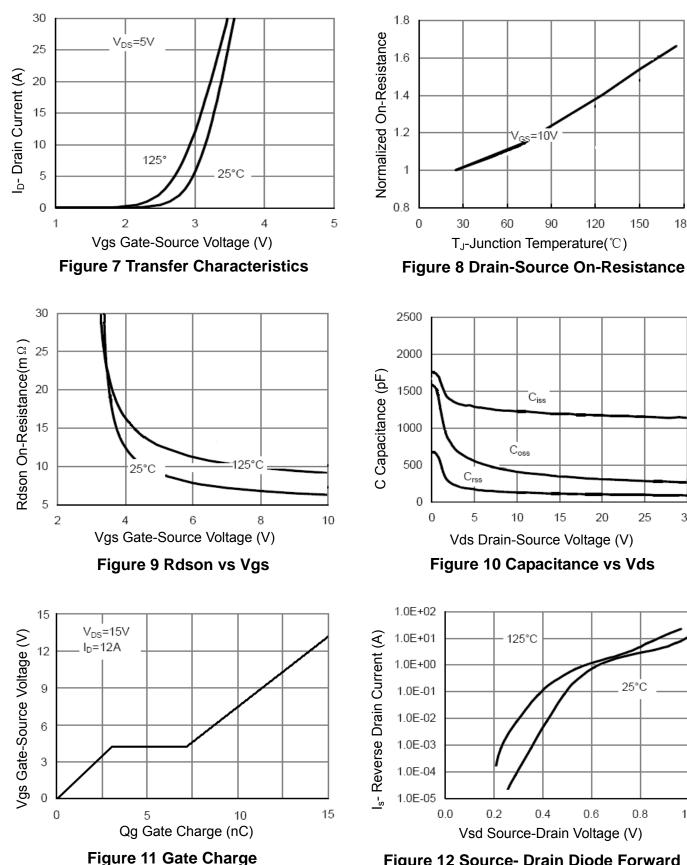
25

25°C

8.0

30

180



1.0



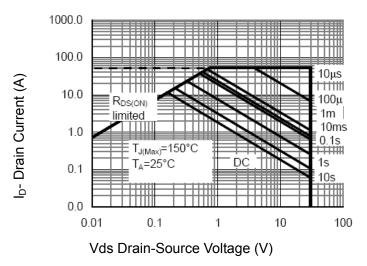
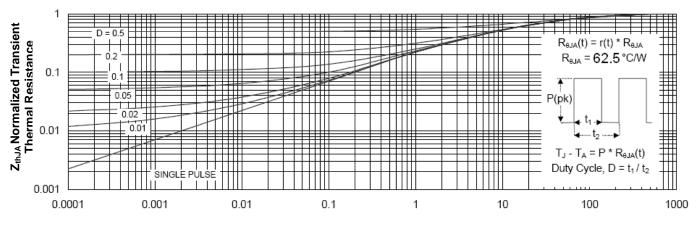


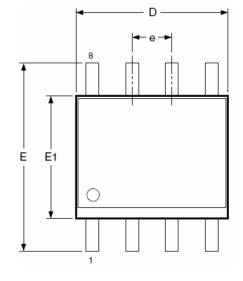
Figure 13 Safe Operation Area

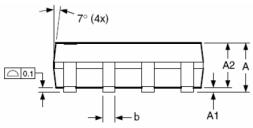


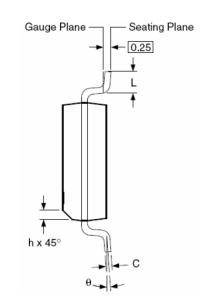
Square Wave Pluse Duration(sec) Figure 14 Normalized Maximum Transient Thermal Impedance



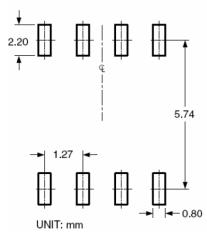
SOP-8 PACKAGE INFORMATION







RECOMMENDED LAND PATTERN



Dimensions in millimeters					
Symbols	Min.	Nom.	Max.		
A	1.35	1.65	1.75		
A1	0.10	—	0.25		
A2	1.25	1.50	1.65		
b	0.31	—	0.51		
С	0.17	—	0.25		
D	4.80	4.90	5.00		
E1	3.80	3.90	4.00		
е		1.27 BSC)		
E	5.80	6.00	6.20		
h	0.25	_	0.50		
L	0.40	_	1.27		
θ	0 °	—	8°		

6

Dimensions in inches

Symbols	Min.	Nom.	Max.	
Α	0.053	0.065	0.069	
A1	0.004	—	0.010	
A2	0.049	0.059	0.065	
b	0.012	—	0.020	
с	0.007	—	0.010	
D	0.189	0.193	0.197	
E1	0.150	0.154	0.157	
е	0.050 BSC			
E	0.228	0.236	0.244	
h	0.010	_	0.020	
L	0.016	—	0.050	
θ	0 °	—	8 °	

NOTES:

- Dimensions are inclusive of plating
 Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 6 mils.
- 3. Dimension L is measured in gauge plane.
- 4. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.



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